



Photo-receiver Amplifier

General Description

The epc13x family products are monolithic, integrated high sensitive photo-diode amplifiers for light-barrier, light-curtain, and the like applications. It amplifies current pulses from reverse-biased PIN photodiodes (e.g. BP104 by OSRAM) and discriminates the amplified input light pulse before driving the open-drain output stage. The device is controlled by an internal digital controller, which uses no external clock signal. The power supply of the device can be connected in anti-polar mode to decrease the wiring effort in matrix operated light-curtain products. The device has been optimized to utilize the least count of external components.

This device allows the design of short to long range light barriers from a few millimeters up to tens of meters.

epc130/epc131 are the same devices but with an analog output. Please refer to the corresponding data sheet epc130/epc131.

Features

- Low current consumption
- Digital output
- Reverse polarity protection
- Two-wire and open drain output interface
- High sensitivity (epc135/138)
- Fast versions available (epc136/139)
- Light reserve output (epc135/136)
- High sensitivity and light reserve output (epc134)
- CSP6 package with very small footprint and standard QFN16 package available

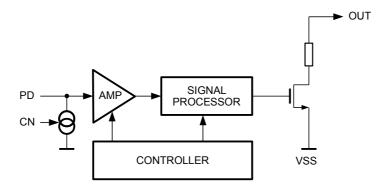
Applications

- Light barriers ranging from millimeters to tens of meters
- Light curtains
- Smoke detectors
- Liquid detectors
- Heart beat monitors

Device selection table

Model	Output		Light Reserve Output		Response Time		Sensitivity			
	digital	analog	w/o	with	slow	fast	low	medium	high	very high
epc130		x	x		×					
epc131		x	x			x				
ерс134	x			x		x		x		
ерс135	x			x	x				x	
ерс136	x			x		x	x			
ерс137	x		x		x					x
ерс138	x		x		x				x	
ерс139	x		x			x	x			

Functional Block Diagram





Absolute Maximum Ratings	Maximum Ratings (Notes 1, 2) Recommende			d Operating Conditions				
Power Supply Voltage V _{DD}	-5.5V to +5.5V		Min.	Max.	Units			
Voltage to Any pin	-0.3 to V_{DD} +0.3V	Power Supply Voltage (V _{DD})	4.0	5.2	V			
Maximum Power Dissipation	300mW							
Storage Temperature Range (T _s)	-40°C to +85°C	Operating Temperature (T _A)	-40°	+85°	С			
Lead Temperature solder, 4 sec. (T _L)	+260°C	Humidity	+5	+95	%			

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Recommended operating conditions indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see Electrical Characteristics.

Note 2: This device is a highly sensitive CMOS ac current amplifier with an ESD rating of JEDEC HBM class 0 (<250V). Handling and assembly of this device should only be done at ESD protected workstations.

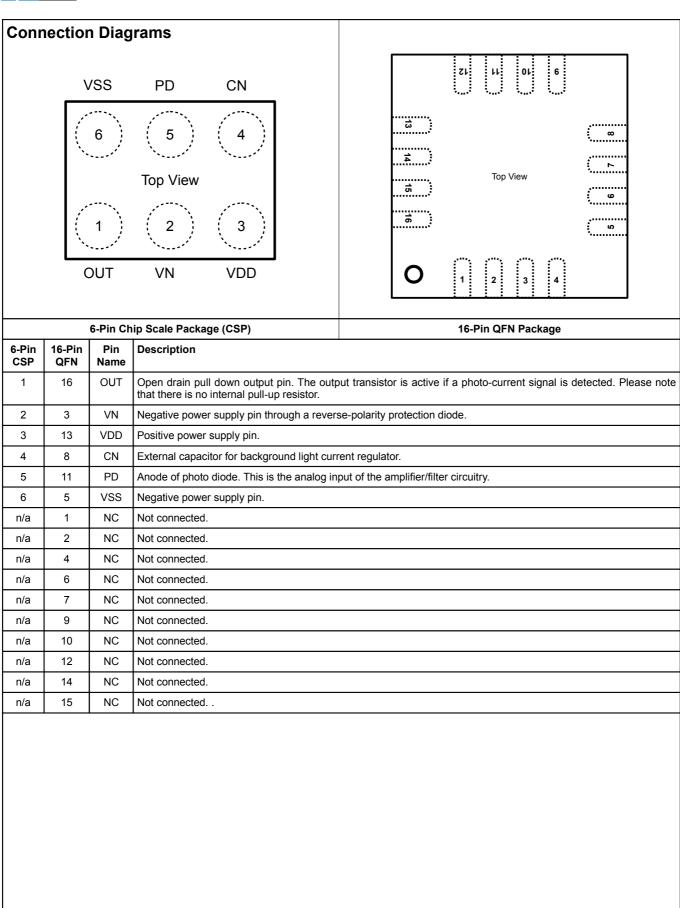
Electrical Characteristics

 $V_{DD} = 5.0 \text{ V}, -40^{\circ}\text{C} < T_A < +85^{\circ}\text{C}$

Symbol	Parameter		Conditions/Comments	Values			Units
				Min.	Тур.	Max.	
V_{PP}	Ripple on Supply Voltage	epc135 epc138	Sinusoidal 100kHz, refer to other parameters			40	mV _{pp}
		epc137				22	
		epc136 epc139	Sinusoidal 800kHz, refer to other parameters			110	
		epc134				45	
I_{DD}	Power Supply Current	All slow	no photo diode current		0.45	0.50	mA
		All fast			0.75	0.80	
V_{PD}	Reversed Photodiode Voltaç	ge	relative to VDD		VDD- 1.55		٧
I_{PD}	Input Pulse Threshold	epc137	Photodiode current pulse to generate an output pulse		40		nA
	(Sensitivity)	epc135 epc138		60	80	100	nA
		epc134]	200	400	600	nA
		epc136 epc139		600	800	1000	nA
I _{PDres}	Input Pulse Threshold Reserve	epc134 - epc137	Input pulse current relative to I _{PD} to trigger the light reserve output		150		%
PDmax	Input Pulse Current		If input current is above this level, recovery time t_{REC} is undefined (refer to section 'Other Parameters')			100	μA
I _{PDDC}	DC Light Current Range	•	refer to section 'Application Information, Ambient Light'	0.0		3.0	mA
C_{PD}	Photodiode Capacitance	epc135 epc137 epc138	refer to section 'Application Information, Photodiode Capacitance'	15		50	pF
		epc134 epc136 epc139		30		40	
I _{out}	Output Current (sink)	•	When a light pulse above the threshold is detected	-6.0	-8.0	-10.0	mA
V_{POR}	Power-up Threshold Voltage		The voltage at VDD when the device starts up and the startup time is running.	3.0	3.5	4.0	V
V_{IPOR}	Hysteresis		on Power-up Threshold Voltage	0.5	0.75	1.0	V
t _{INIT}	Power-up Startup Time		VDD slew rate >100V/ms			1.5	ms
t _{OFF}	Power-down Time					1.5	ms



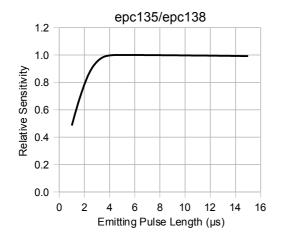
Sym- bol	Parameter		Conditions/Comments	Values			Units
				Min.	Тур.	Max.	
t _{REC}	Recovery Time	epc135 epc137 epc138	After the reception of a pulse current (100nA <i<sub>PD<100μA) at pin PD until a next pulse can be detected. It is to note that a higher input current</i<sub>	80	110	130	μs
		epc134 epc136 epc139	pulse may lead to a secondary output pulse and thus a longer recovery time.			25	
t _{out}	Output Pulse Width at pin OUT	epc135 epc137 epc138	When a valid pulse at pin PD is detected.	17	22	28	μѕ
		epc134 epc136 epc139		1.5	2.0	2.5	
t _{PD} Inp	-	epc135 epc137 epc138	Current pulse width at pin PD necessary to generate an output pulse at pin OUT. The input sensitivity is dependent on the input current pulse width (refer to the section Applications and Other Parameters).		6		μs
		epc134 epc136 epc139			0.75		
t _{rf}	Input pulse slew rate	epc135 epc137 epc138	maximum rise and fall time of the current pulse at pin PD in order to achieve the stated sensitivity.		500		ns
		epc134 epc136 epc139			50		
R _{PD}	Photodiode bias resistor	epc135 epc137 epc138	refer to section 'Application Information, Photodiode Resistor'		27		kΩ
		epc134			6.8		
		epc136 epc139			4.7		

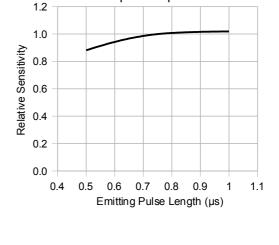




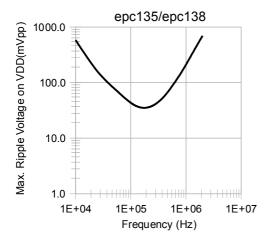
Other Parameters

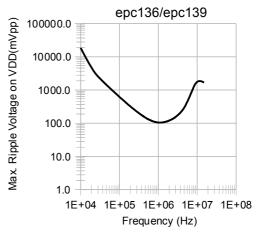
(typical values, $T_{amb} = 25^{\circ}C$, $V_{DD} = 5.0V$)





epc136/epc139

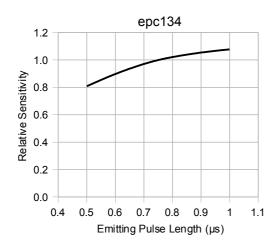


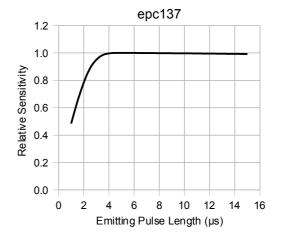


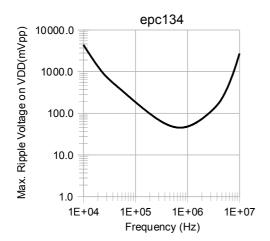
Max. ripple voltage on VDD until output is triggered

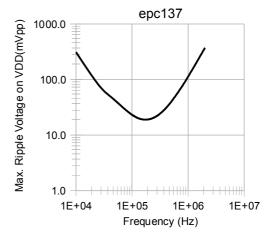
Max. ripple voltage on VDD until output is triggered











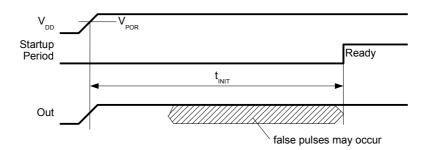
Max. ripple voltage on VDD until output is triggered

Max. ripple voltage on VDD until output is triggered

Functional Description

Power-up Sequence

If V_{DD} reaches V_{POR} , the startup sequence is initiated. After the time t_{DEL} , the photo diode bias circuit is enabled. Thus, a current generated by light on the photo diode flows into the pin PD. After the time tlNIT, the device is ready to receive AC light pulses.



Power-up sequence

Power-down Sequence

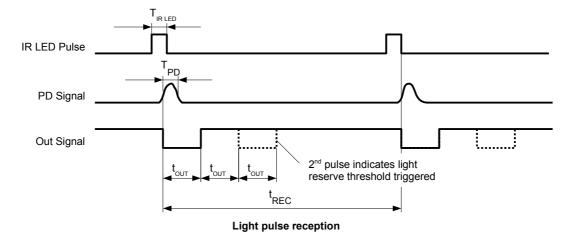
When VDD goes down, the device is turned off when V_{DD} is below V_{POR} minus V_{IPOR} .



Power-down sequence

Light Pulse Reception

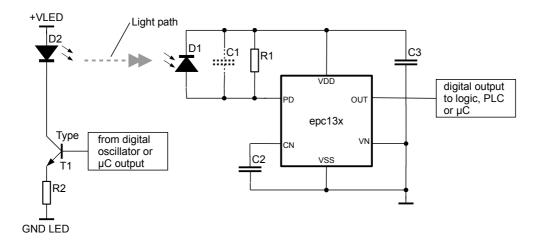
A light pulse on the photo diode generates a current puls into the pin PD of the device. If the current pulse exceeds the threshold I $_{PD}$, an output pulse is generated. The length of the output pulse is given by t_{Out} . After a waiting time given by t_{REC} , the next light pulse can be sent. If the waiting time is too short, the device is not ready to receive the next pulse. Thus, no output pulse is appears at pin OUT.



Application Information

Light Barrier Application

The following circuit is recommended to operate the epc134/135/136/137/138/139 as a photo diode amplifier in a single beam light barrier:



Recommended Components Values

- R1: 27k(epc135/137/138), 6.8k(epc134) and 4.7k (epc136/139) (bias resistor). Sensitivity can be reduced by the reduction of this resistor.
- R2: dependent on the required LED current
- C1: Usually not needed. May be up to 100 pF (refer to section 'Photodiode Capacitance'). C2: 33nF (DC input current filter capacitor)
- C3: 100nF or greater (power supply filter capacitor)
- D1: PIN photo diode, BP104 (OSRAM) or similar devices
- D2: IR LED, TSML1000 (Vishay) or similar devices

Working Principle

The IR LED D2 emits light pulses which are sent towards the photo diode D1. If there is no obstacle between the two devices, the light pulse generates an AC current (I_{PD}) in the reverse biased photo diode D1 into the pin PD. I_{PD} is proportional to the power of the light pulse. If I_{PD} is greater than the trigger threshold of the circuitry in the device, a pulse at the pin OUT is generated. If IPD is greater than the trigger threshold for the light reserve (I_{PDres}), a second pulse at the output is generated. The length of the output pulse is given by t_{OUT}. Once a light pulse is generated by the IR LED, a next light pulse must not be generated until the recovery time t REC (max.).

Design Precautions

The sensitivity at pin PD is very high in order to achieve a long operation range of light barriers even without lenses in front of the IR LED and/or the photo diode. Thus, the pin PD is very sensitive to EMI. Special care should be taken to keep the PCB track at pin PD as short as possible (a few mm only!). This track should be kept away from the IR LED signal tracks and from other sources which may induce unwanted signals. It is strongly recommended to cover the chip, the photodiode and all passive components around the chip with a metal shield. A recommended part is shown in the following figure:

The pins at the bottom are to solder the shield to the PCB with electrical connection to VDD. The hole in the front is the opening window for the photo diode. The back side of the PCB below the sensitive area (D1, C1, R1, epc13x) shall be a polygon connected to VDD to shield the circuit from the back side. C1 must be of high mechanical stability (no piezoelectric effect) in order to avoid unwanted signals by mechanical shock or vibration.



Recommended EMC shield

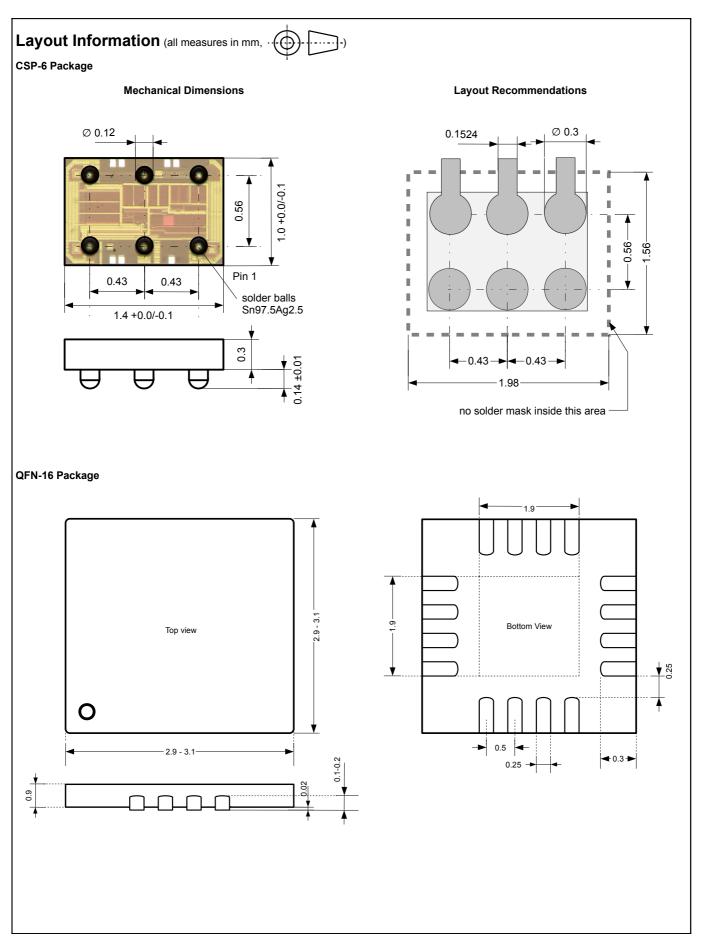
Ambient Light

Photodiode DC current can be generated by ambient light, e.g. sun light. DC currents at pin PD do not generate an output signal. However, if I_{PDDC} is above the stated value, the input is saturated which blocks the detection of AC current pulses.

Photodiode Capacitance

If the photodiode capacitance is below the specified value, the system becomes more sensitive to power supply ripple voltage at higher frequencies (>200kHz). This sensitivity can be reduced by a parallel capacitor to the photodiode. However, this measure reduces the detection sensitivity. If the photo diode capacity is above the specified value, a lower detection sensitivity and a higher sensitivity spread results.





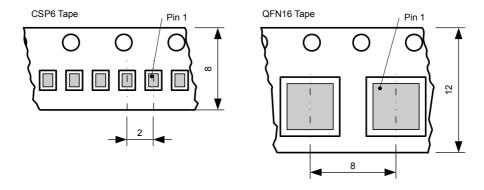
Reflow Solder Profile

For infrared or conventional soldering the solder profile has to follow the recommendations of IPC/JEDEC J-STD-020C (min. revision C) for Pb-free assembly for both types of packages. The peak soldering t emperature (T_L) should not exceed +260°C for a maximum of 4 sec.

Packaging Information (all measures in mm)

Tape & Reel Information

The devices are mounted on embossed tape for automatic placement systems. The tape is wound on 178 mm (7 inch) or 330 mm (13 inch) reels and individually packaged for shipment. General tape-and-reel specification data are available in a separate data sheet and indicate the tape sizes for various package types. Further tape-and-reel specifications can be found in the Electronic Industries Association (EIA) standard 481-1, 481-2, 481-3.



epc does not guarantee that there are no empty cavities. Thus, the pick-and-place machine should do check the presence of a chip during picking.

Order Information

Part Number	Package	RoHS compliance	Packaging Method
epc134-CSP6	CSP6	Yes	Reel
epc134-QFN16	QFN16	Yes	Reel
epc135-CSP6	CSP6	Yes	Reel
epc135-QFN16	QFN16	Yes	Reel
epc136-CSP6	CSP6	Yes	Reel
epc136-QFN16	QFN16	Yes	Reel
epc137-CSP6	CSP6	Yes	Reel
epc137-QFN16	QFN16	Yes	Reel
epc138-CSP6	CSP6	Yes	Reel
epc138-QFN16	QFN16	Yes	Reel
epc139-CSP6	CSP6	Yes	Reel
epc139-QFN16	QFN16	Yes	Reel

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